2.5" SATA SSD

3MG2-P Series

innodisk

Total Solution For Industrial Flash Storage

Customer:

Customer Part Number:

Innodisk Part Number:

Innodisk Model Name:

Date:

Innodisk Approver	Customer Approver

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REVISION HISTORY

Revision	Description	Date
Preliminary	First Released	July, 2014
Rev 1.0	Add 1TB LBA Update ME drawing Update Performance	August, 2014
Rev 1.1	Add CE/FCC	August, 2014
Rev 1.2	Modify TBW info.	October, 2014
Rev 1.3	Update ME info.	October, 2014
Rev 2.0	Support Micron MLC Add 9.2mm height housing info.	December, 2014
Rev 2.1	Remove flash endurance SPEC	Jan., 2015
Rev 2.1.1	Modify part number rule	Jan., 2015
Rev 2.2	Update performance of Micron solution	Feb., 2015
Rev 2.3	Update performance of Micron solution	Apr., 2015
Rev 2.4	Update ME drawing Modify 8GB/16GB LBA	Apr., 2015
Rev 2.5	Add SMART feature set	May, 2015
Rev 2.6	Update TBW Update random performance	May, 2015
Rev 2.7	Add iCell function (optional)	Jul., 2015
Rev 2.8	Add Quick erase function (optional)	Jul., 2015
Rev 3.0	Add 2TB	Oct., 2015
Rev 3.1	Update part number rule for Toshiba 15nm	Oct., 2015
Rev 3.2	Update Performance for Toshiba 15nm	Dec., 2015
Rev 3.3	Add 1TB performance with 15nm Update 2TB performance	Jan., 2016
Rev 3.4	Update part number of Mechanical Dimensions Update 15nm performance	Feb., 2016
Rev 4.0	Update Performance for 15nm	Apr., 2016
Rev 4.1	Add Quick erase time	Jun., 2016
Rev 4.2	Update Performance Update RoHS/REACH	Aug., 2016
Rev 4.2.1	Update power consumption	Oct., 2016
Rev 4.2.2	Correct write power consumption of 2TB	Dec., 2016
Rev 5.0	Update TBW and test workload Remove Toshiba A19 performance	Mar., 2017
Rev 5.1	Add Torque value for M3 Screw	June, 2017

	Update CE/FCC Certification	
Rev 5.2	Modify Quick erase function	Aug.,2018
Rev 5.2.2	Add different configuration of 512GB (Micron)	Nov.,2018
Rev 5.3	Add TRIM note Update RoHS report	Apr.,2019

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1. Product Overview

1.1 Introduction of Innodisk 2.5" SATA SSD 3MG2-P

Innodisk 2.5" SATA SSD 3MG2-P products provide high capacity flash memory Solid State Drive (SSD) that electrically complies with Serial ATA (SATA) standard. It supports SATA III standard (6.0GHz) with high performance. Innodisk 2.5" SATA SSD 3MG2-P is designed for industrial field, and supports several standard features, including TRIM, NCQ, and S.M.A.R.T. The SSD have good performance, no latency time and small seek time. It effectively reduces the booting time of operation system and the power consumption is less than hard disk drive (HDD).

CAUTION *TRIM must be enabled.*

TRIM enables SSD's controller to skip invalid data instead of moving. It can free up significant amount of resources, extends the lifespan of SSD by reducing erase, and write cycles on the SSD. Innodisk's handling of garbage collection along with TRIM command improves write performance on SSDs.

1.2 Product View and Models

Innodisk 2.5" SATA SSD 3MG2-P is available in follow capacities:

2.5" SATA SSD 3MG2-P 8GB	2.5" SATA SSD 3MG2-P 128GB
2.5" SATA SSD 3MG2-P 16GB	2.5" SATA SSD 3MG2-P 256GB
2.5" SATA SSD 3MG2-P 32GB	2.5" SATA SSD 3MG2-P 512GB
2.5" SATA SSD 3MG2-P 64GB	2.5" SATA SSD 3MG2-P 1TB
2.5" SATA SSD 3MG2-P 2TB	

Figure 1: Innodisk 2.5" SATA SSD 3MG2-P

1.3 SATA Interface

Innodisk 2.5" SATA SSD 3MG2-P supports SATA III interface, and compliant with SATA I and SATA II. SATA III interface can work with Serial Attached SCSI (SAS) host system, which is used in server computer. Innodisk 2.5" SATA SSD 3MG2-P is compliant with Serial ATA Gen 1, Gen 2 and Gen 3 specification (Gen 3 supports 1.5Gbps /3.0Gbps/6.0Gbps data rate). SATA connector uses a 7-pin signal segment and a 15-pin power segment.

1.4 2.5-inch Form Factor

The Industry-standard 2.5-inch form factor design with metal material case is easy for installation, which has a compact design 69.85mm (W) x 100.00mm (L) x 6.90mm (H)/ 70.00mm (W) x100.00mm (L) x 6.80mm (H)/69.85mm (W) x 100.00mm (L) x 9.50mm (H).

2. Product Specifications

2.1 Capacity and Device Parameters

2.5" SATA SSD 3MG2-P device parameters are shown in Table 1.

Table 1: Device parameters

Capacity	LBA	Cylinders	Heads	Sectors	User Capacity(MB)
8GB	13695696	13587	16	63	6687
16GB	29323728	16383	16	63	14318
32GB	60579792	16383	16	63	29580
64GB	121138416	16383	16	63	59150
128GB	242255664	16383	16	63	118289
256GB	484490160	16383	16	63	236567
512GB	968959152	16383	16	63	473124
1TB	1937897136	16383	16	63	946238
2TB	3875733504	16383	16	63	1892448

2.2 Performance

Burst Transfer Rate: 6.0Gbps

Table 2: Performance

	Capacity	8GB (1CH)	16GB (1CH)	16GB (2CH)	32GB (2CH)	32GB (4CH)	64GB (4CH)	128GB (4CH)	256GB (4CH)
Toshiba 15nm **(Slim inside)**	Sequential* Read (max.)	140 MB/s	140 MB/s	270 MB/s	270 MB/s	520 MB/s	520 MB/s	520 MB/s	520 MB/s
	Sequential Write (max.)	25 MB/s	25 MB/s	45 MB/s	45 MB/s	90 MB/s	90 MB/s	180 MB/s	350 MB/s
	4KB Random Read (QD32)	14,000 IOPS	14,000 IOPS	27,000 IOPS	27,000 IOPS	52,000 IOPS	52,000 IOPS	67,000 IOPS	75,000 IOPS
	4KB Random Write (QD32)	6400 IOPS	6400 IOPS	11,500 IOPS	11,500 IOPS	23,000 IOPS	23,000 IOPS	46,000 IOPS	83,000 IOPS

	Capacity	8GB (1CH)	16GB (1CH)	16GB (2CH)	32GB (2CH)	32GB (4CH)	64GB (4CH)	128GB (4CH)	256GB (4CH)	512GB (4CH)	1TB (4CH)	2TB (4CH)
Toshiba 15nm **(Full PCBA; w/iCell)**	Sequential* Read (max.)	140 MB/s	140 MB/s	270 MB/s	270 MB/s	520 MB/s	520 MB/s	520 MB/s	520 MB/s	520 MB/s	520 MB/s	510 MB/s
	Sequential Write (max.)	25 MB/s	25 MB/s	45 MB/s	45 MB/s	90 MB/s	180 MB/s	350 MB/s	350 MB/s	450 MB/s	450 MB/s	450 MB/s
	4KB Random Read (QD32)	14,000 IOPS	14,000 IOPS	27,000 IOPS	27,000 IOPS	52,000 IOPS	75,000 IOPS	75,000 IOPS	75,000 IOPS	75,000 IOPS	75,000 IOPS	9,000 IOPS
	4KB Random Write (QD32)	6400 IOPS	6400 IOPS	11,500 IOPS	11,500 IOPS	23,000 IOPS	46,000 IOPS	80,000 IOPS	83,000 IOPS	76,000 IOPS	78,000 IOPS	28,000 IOPS

Note: *Performance based on CrystalDiskMark 3.03with file size 1000M

	Capacity	64GB	128GB	256GB	512GB (512Gb x8)	512GB (256Gb x16)	1TB	2TB
Micron	Sequential Read (max.)	440 MB/s	510 MB/s	520 MB/s	520 MB/s	520 MB/s	520 MB/s	440 MB/s
	Sequential Write (max.)	70 MB/s	140 MB/s	300 MB/s	300 MB/s	450 MB/s	450 MB/s	420 MB/s
	4KB Random Read (QD32)	70,000 IOPS	70,000 IOPS	70,000 IOPS	70,000 IOPS	70,000 IOPS	70,000 IOPS	9,000 IOPS
	4KB Random Write (QD32)	17,000 IOPS	35,000 IOPS	64,000 IOPS	64,000 IOPS	64,000 IOPS	64,000 IOPS	26,000 IOPS

Note: *Performance based on CrystalDiskMark 3.03 with file size 1000M

2.3 Electrical Specifications

2.3.1 Power Requirement

Table 3: Innodisk 2.5" SATA SSD 3MG2-P Power Requirement

Item	Symbol	Rating	Unit
Input voltage	V_{IN}	+5 DC +- 5%	V

2.3.2 Power Consumption

Table 4: Power Consumption

Mode	Power Consumption
Read	122 mA (max.)
Write	429 mA (max.)
Idle	84 mA (max.)
DEVSLP Mode	3mW (min.)
Slumber Mode	30mW (min.)

* Target: 2.5" SATA SSD 3MG2-P 256GB

Mode	Power Consumption
Read	708 mA (max.)
Write	1155 mA (max.)
Idle	374 mA (max.)

* Target: 2.5" SATA SSD 3MG2-P 2TB

2.4 Environmental Specifications

2.4.1 Temperature Ranges

Table 5: Temperature range for 2.5" SATA SSD 3MG2-P

Temperature	Range
Operating	Standard Grade: 0°C to +70°C
	Industrial Grade:-40°C to +85°C
Storage	-55°C to +95°C

2.4.2 Humidity

Relative Humidity: 10-95%, non-condensing

2.4.3 Shock and Vibration

Table 6: Shock/Vibration Testing for 2.5" SATA SSD 3MG2-P

Reliability	Test Conditions	Reference Standards
Vibration	7 Hz to 2K Hz, 20G, 3 axes	IEC 68-2-6
Mechanical Shock	Duration: 0.5ms, 1500 G, 3 axes	IEC 68-2-27

2.4.4 Mean Time between Failures (MTBF)

Table 7 summarizes the MTBF prediction results for various 2.5" SATA SSD 3MG2-P configurations. The analysis was performed using a RAM Commander™ failure rate prediction.

· **Failure Rate**: The total number of failures within an item population, divided by the total number of life units expended by that population, during a particular measurement interval

under stated condition.

- **Mean Time between Failures (MTBF)**: A basic measure of reliability for repairable items: The mean number of life units during which all parts of the item perform within their specified limits, during a particular measurement interval under stated conditions.

Table 7: 2.5" SATA SSD 3MG2-P MTBF

Product	Condition	MTBF (Hours)
Innodisk 2.5" SATA SSD 3MG2-P	Telcordia SR-332 GB, 25°C	>3,000,000

2.5 CE and FCC Compatibility

2.5" SATA SSD 3MG2-P conforms to CE and FCC requirements.

2.6 RoHS Compliance

2.5" SATA SSD 3MG2-P is fully compliant with RoHS directive.

2.7 Reliability

Parameter	Value	
Read Cycles	Unlimited Read Cycles	
Flash endurance	3,000 P/E cycles	
Wear-Leveling Algorithm	Support	
Bad Blocks Management	Support	
Error Correct Code	Support	
TBW* (Total Bytes Written) Unit:TB		
Capacity	**Sequential workload**	**Client workload**
08GB	21.3	9.4
16GB	42.6	18.8
32GB	85.2	37.5
64GB	170.5	75
128GB	340.9	150
256GB	681.8	300
512GB	1364	600
1TB	2663	1172
2TB	5327	2344

*Note:

1. Sequential: Mainly sequential write, tested by Vdbench.

2. Client: Follow JESD218 Test method and JESD219A Workload, tested by ULINK. (The capacity lower than 64GB client workload is not specified in JEDEC219A, the values are estimated.)

3. Based on out-of-box performance.

2.8 Transfer Mode

2.5" SATA SSD 3MG2-P support following transfer mode:

Serial ATA III 6.0Gbps

Serial ATA II 3.0Gbps

Serial ATA I 1.5Gbps

2.9 Pin Assignment

Innodisk 2.5" SATA SSD 3MG2-P uses a standard SATA pin-out. See Table 8 for 2.5" SATA SSD 3MG2-P pin assignment.

Table 8: Innodisk 2.5" SATA SSD 3MG2-P Pin Assignment

Name	Type	Description
S1	GND	NA
S2	A+	Differential Signal Pair A
S3	A-	
S4	GND	NA
S5	B-	Differential Signal Pair B
S6	B+	
S7	GND	NA
Key and Spacing separate signal and power segments		
P1	NC	NA
P2	NC	NA
P3	NC	NA
P4	GND	NA
P5	GND	NA
P6	GND	NA
P7	V5	5V Power, Pre-Charge
P8	V5	5V Power
P9	V5	5V Power
P10	GND	NA
P11	DAS/DSS	Device Activity Signal / Disable Staggered
P12	GND	NA
P13	NC	NA
P14	NC	NA
P15	NC	NA

2.10 Mechanical Dimensions

* DGS25-XXXD81BX1(A)XX(P)
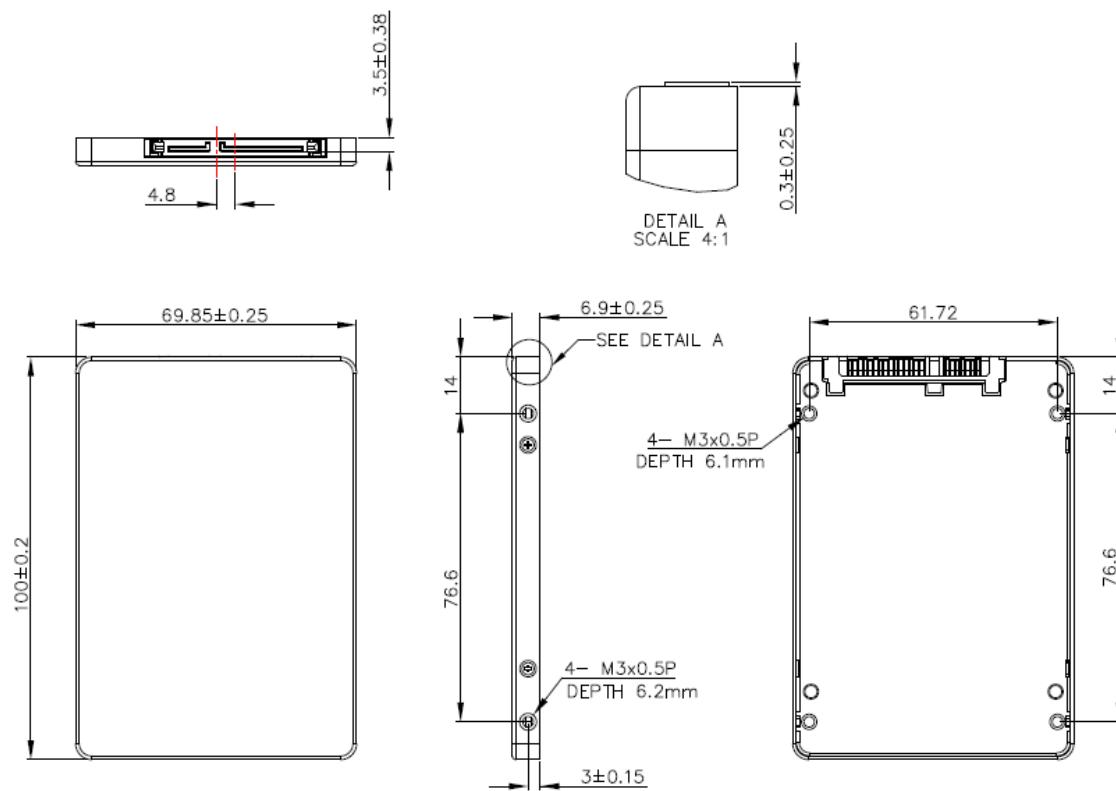
* DGS25-XXXD81BX2XX(P)

* DGS25-XXXD81BX3XX

DETAIL A
SCALE 4:1

SEE DETAIL A

M3x4

M3x4
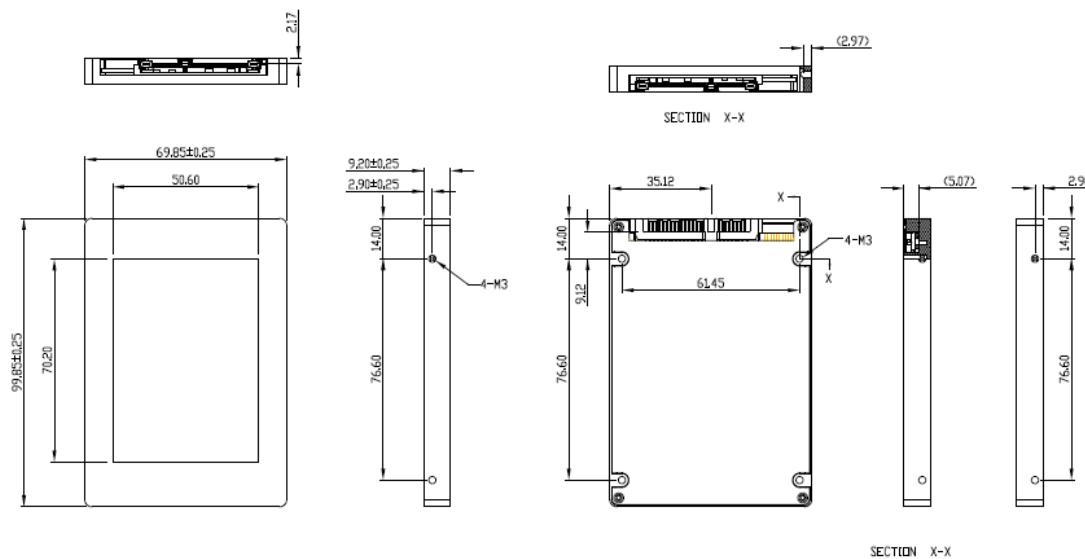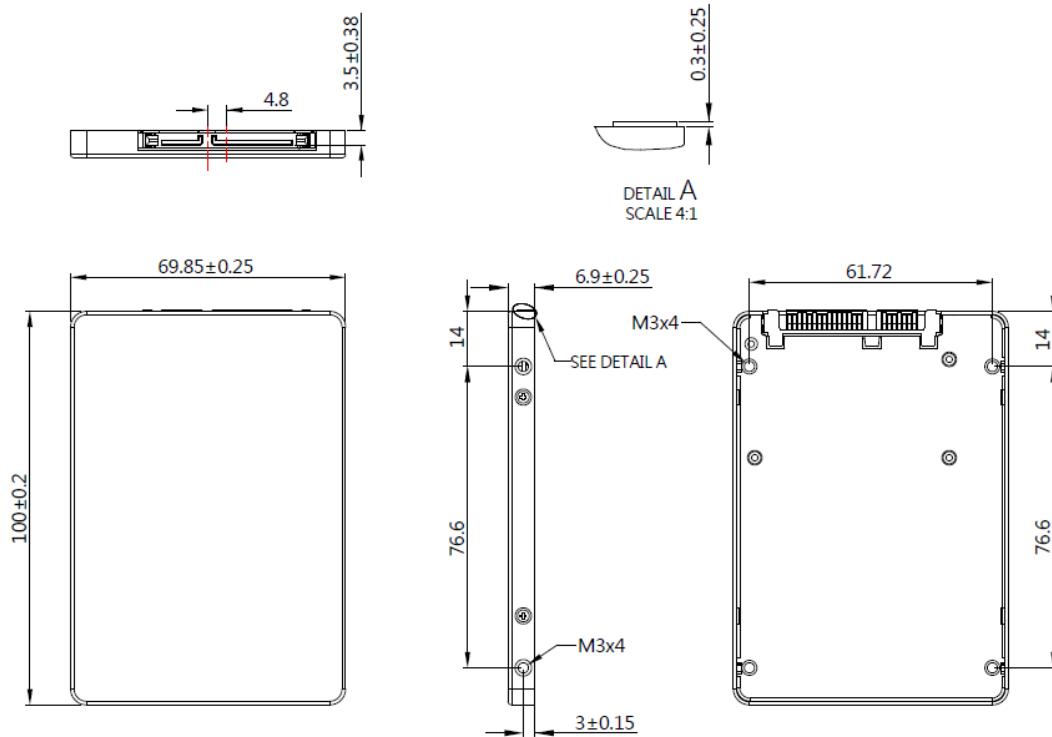
*DGS25-02TD81SXAXX/ DGS25-02TD81BXAXX

DETAIL A
SCALE 4:1

SEE DETAIL A

4- M3x0.5P
(DEPTH 8.5mm)

4- M3x0.5P
(DEPTH 6.2mm)
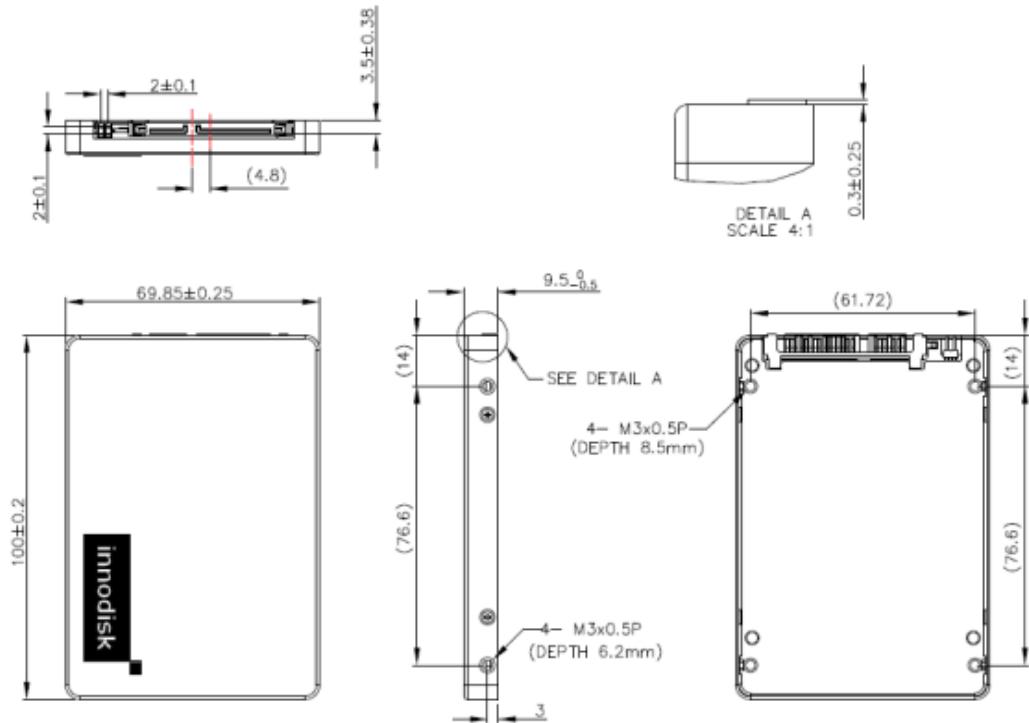
2.11 Assembly Weight

An Innodisk 2.5" SATA SSD 3MG2-P within MLC flash ICs, 2TB's weight is 90 grams approx.

2.12 Seek Time

Innodisk 2.5" SATA SSD 3MG2-P is not a magnetic rotating design. There is no seek or rotational latency required.

2.13 Hot Plug

The SSD support hot plug function and can be removed or plugged-in during operation. User has to avoid hot plugging the SSD which is configured as boot device and installed operation system.

Surprise hot plug   : The insertion of a SATA device into a backplane (combine signal and power) that has power present. The device powers up and initiates an OOB sequence.

Surprise hot removal: The removal of a SATA device from a powered backplane, without first being placed in a quiescent state.

2.14 NAND Flash Memory

Innodisk 2.5" SATA SSD 3MG2-P uses Multi Level Cell (MLC) NAND flash memory, which is non-volatility, high reliability and high speed memory storage.

3. Theory of Operation

3.1 Overview

Figure 2 shows the operation of Innodisk 2.5" SATA SSD 3MG2-P from the system level, including the major hardware blocks.
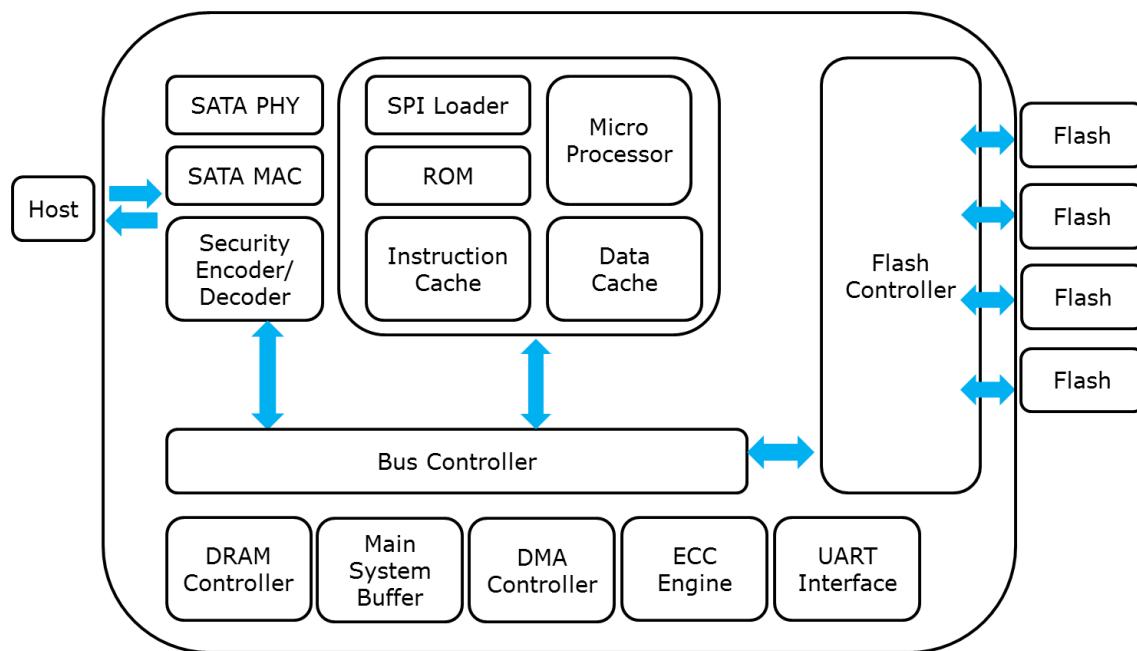

Figure 2: Innodisk 2.5" SATA SSD 3MG2-P Block Diagram

Innodisk 2.5" SATA SSD 3MG2-P integrates a SATA III controller and NAND flash memories. Communication with the host occurs through the host interface, using the standard ATA protocol. Communication with the flash device(s) occurs through the flash interface.

* iCell is optional feature with different part number.

3.2 SATA III Controller

Innodisk 2.5" SATA SSD 3MG2-P is designed with ID 201, a SATA III 6.0Gbps (Gen. 3) controller, which supports external DDR3 DRAM. The Serial ATA physical, link and transport layers are compliant with Serial ATA Gen 1, Gen 2 and Gen 3 specification (Gen 3 supports 1.5Gbps/3.0Gbps/6.0Gbps data rate). The controller has 4 channels for flash interface.

3.3 Error Detection and Correction

Highly sophisticated Error Correction Code algorithms are implemented. The ECC unit consists of the Parity Unit (parity-byte generation) and the Syndrome Unit (syndrome-byte computation).

This unit implements an algorithm that can correct 66 bits per 1024 bytes in an ECC block. Code-byte generation during write operations, as well as error detection during read operation, is implemented on the fly without any speed penalties.

3.4 Wear-Leveling

Flash memory can be erased within a limited number of times. This number is called the **erase cycle limit** or **write endurance limit** and is defined by the flash array vendor. The erase cycle limit applies to each individual erase block in the flash device.

Innodisk 2.5" SATA SSD 3MG2-P uses a static wear-leveling algorithm to ensure that consecutive writes of a specific sector are not written physically to the same page/block in the flash. This spreads flash media usage evenly across all pages, thereby extending flash lifetime.

3.5 Bad Blocks Management

Bad Blocks are blocks that contain one or more invalid bits whose reliability are not guaranteed. The Bad Blocks may be presented while the SSD is shipped, or may develop during the life time of the SSD. When the Bad Blocks is detected, it will be flagged, and not be used anymore. The SSD implement Bad Blocks management, Bad Blocks replacement, Error Correct Code to avoid data error occurred. The functions will be enabled automatically to transfer data from Bad Blocks to spare blocks, and correct error bit.

3.6 iData Guard

Innodisk's iData Guard is a comprehensive data protection mechanism that functions before and after a sudden power outage to SSD. Low-power detection terminates data writing before an abnormal power-off, while table-remapping after power-on deletes corrupt data and maintains data integrity. Innodisk's iData Guard provides effective power cycling management, preventing data stored in flash from degrading with use.

3.7 Garbage Collection/TRIM

Garbage collection and TRIM technology is used to maintain data consistency and perform continual data cleansing on SSDs. It runs as a background process, freeing up valuable controller resources while sorting good data into available blocks, and deleting bad blocks. It also significantly reduces write operations to the drive, thereby increasing the SSD's speed and lifespan.

3.8 iCell Technology (Optional)

iCell circuit is designed with several capacitors to be able to provide power after host power off.

The SSD controller can write all DRAM buffer data to flash, so that is why 2.5" SATA SSD 3MG2-P can ensure all data can be written to disk without any data loss.

3.9 Quick Erase (Optional)

QEraser function is designed for emergency data erase in few seconds by providing ATA command or shorting QEraser Pins (Pin 1 and Pin 2) with an external jumper to erase all of data block.
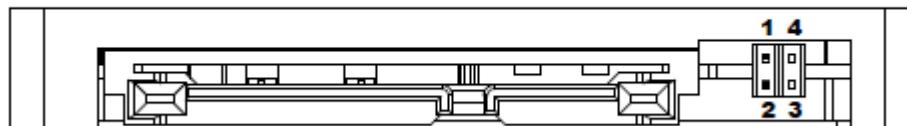
3.9.1 Quick Erase Command

- Protocol: No Data

-Inputs

Table 9: Execute Quick Erase command for inputs information

Register	7	6	5	4	3	2	1	0
Features	21h							
Sector Count	41h							
LBA Low	Na							
LBA Mid	Na							
LBA High	Na							
Device	1	1	1	0	Na			
Command	82h							

-Normal Outputs

Table 10: Quick Erase command for normal output information

Register	7	6	5	4	3	2	1	0
Error	Na							
Sector Count	Na							
LBA Low	Na							
LBA Mid	Na							
LBA High	Na							
Device	obs	Na	obs	DEV	Na	Na	Na	Na
Status	BSY	DRDY	DF	Na	DRQ	Na	Na	ERR

Device register-

    DEV shall specify the selected device.

Status register

BSY will be cleared to zero indicating command completion

DRDY will be set to one.

DF (Device Fault) will be cleared to zero.

DRQ will be cleared to zero

ERR will be cleared to zero.

Table 11: Quick Erase time for Toshiba*

Capacity	Time
8GB	5 Sec.
16GB (1CH)	10 Sec.
16GB (2CH)	5 Sec.
32GB (2CH)	11 Sec.
32GB (4CH)	5 Sec.
64GB	6 Sec.
128GB	7 Sec.
256GB	13 Sec.
512GB	17 Sec.
1TB	34 Sec.

*Note: Based on Asrock H97M anniversary platform.

4. Installation Requirements

4.1 2.5" SATA SSD 3MG2-P Pin Directions

Figure 3: Signal Segment and Power Segment
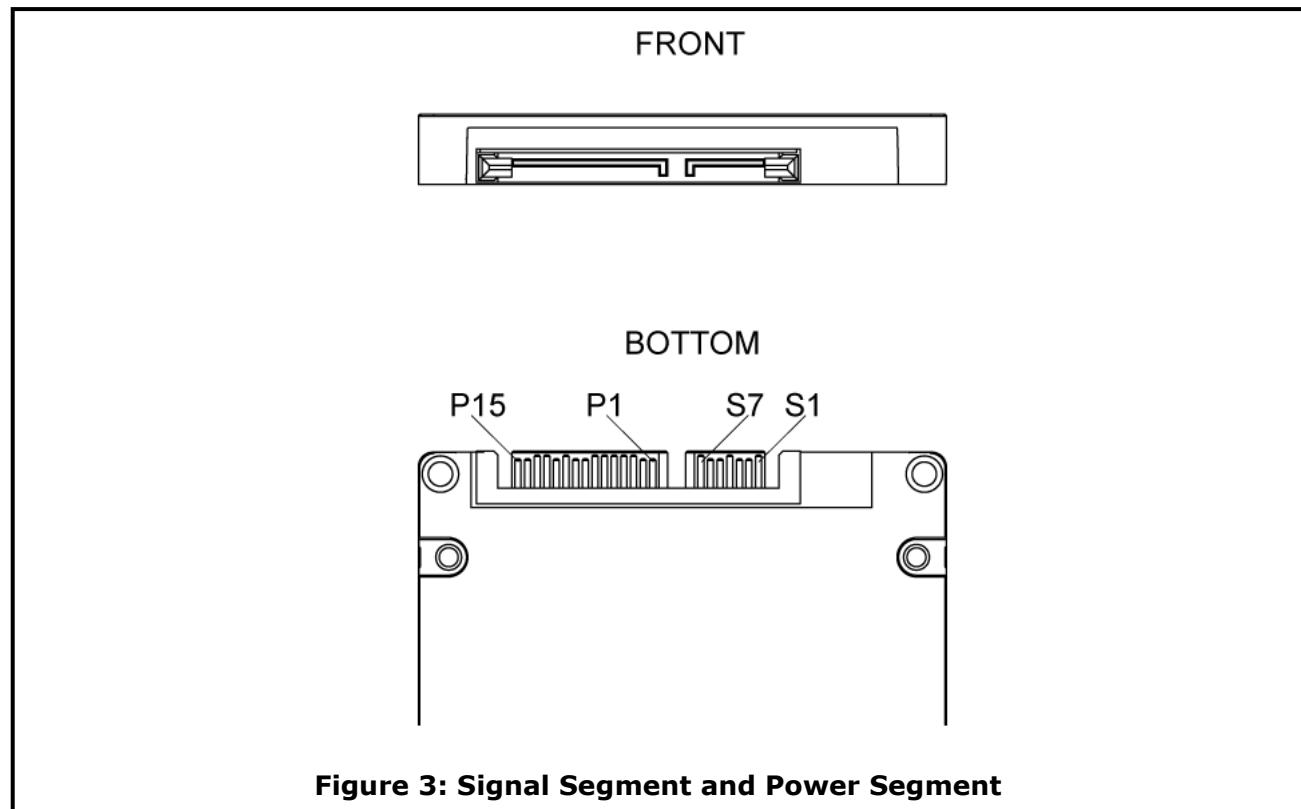
4.2 Electrical Connections for 2.5" SATA SSD 3MG2-P

A Serial ATA device may be either directly connected to a host or connected to a host through a cable. For connection via cable, the cable should be no longer than 1meter. The SATA interface has a separate connector for the power supply. Please refer to the pin description for further details.

4.3 Form Factor

Please prepare following things:

➢ Screw driver.

➢ Four M3 screws. (Suggested torque value is 2.0 ~ 2.5 Kgf.cm)

➢ SATA single cable (7-pin, Maximum length l meter).

➢ SATA power cable (15-pin).

Please turn off your computer, and open your computer's case. Find one of available 2.5-inch slot, and plug the SSD in. To use the screws fix the SSD. Plug in the SATA single cable, and power cable. Please boot the installation Operation System from CD-ROM, and install Operation System into SSD.
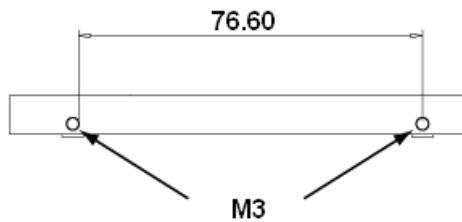
Figure 4: 2.5″ SATA SSD 3MG2-P Mechanical Screw Hole

4.4 Device Drive

No additional device drives are required. Innodisk 2.5″ SATA SSD 3MG2-P can be configured as a boot device.

5. SMART Feature Set

Innodisk 3MG2-P series support the SMART command set and defines some vendor-specific data to report SMART attributes of SSD.

Value	Command
D0h	Read Data
D1h	Read Attribute Threshold
D2h	Enable/Disable Autosave
D3h	Save Attribute Values
D4h	Execute OFF-LINE Immediate
D5h	Read Log
D6h	Return Status
D8h	Enable SMART Operations
D9h	Disable SMART Operations
DAh	Return Status

5.1 SMART Attributes

Innodisk 3MG2-P series SMART data attributes are listed in following table.

Attribute ID (hex)	Raw Attribute Value							Attribute Name
1 (01h)	MSB	00	00	00	00	00	00	Raw Read Error Rate
5 (05h)	LSB	MSB	00	00	00	00	00	Reallocated Sector Count
9 (09h)	LSB			MSB	00	00	00	Power-on Hours
12 (0Ch)	LSB			MSB	00	00	00	Power Cycle Count
160 (A0h)	LSB			MSB	00	00	00	Uncorrectable sector count when read/write
161 (A1h)	LSB	MSB	00	00	00	00	00	Number of valid spare block
163 (A3h)	LSB	MSB	00	00	00	00	00	Number of initial invalid block
164 (A4h)	LSB	MSB	00	00	00	00	00	Total erase count
165 (A5h)	LSB			MSB	00	00	00	Maximum erase count
166 (A6h)	LSB			MSB	00	00	00	Minimum erase count
167 (A7h)	LSB			MSB	00	00	00	Average erase count
168 (A8h)	LSB			MSB	00	00	00	Max erase count of spec
169 (A9h)	LSB			MSB	00	00	00	Remain Life (percentage)
175 (AFh)	LSB			MSB	00	00	00	Program fail count in worst die
176 (B0h)	LSB			MSB	00	00	00	Erase fail count in worst die

177 (B1h)	LSB			MSB	00	00	00	Total wear level count
178 (B2h)	LSB	MSB	00	00	00	00	00	Runtime invalid block count
181 (B5h)	LSB			MSB	00	00	00	Total program fail count
182 (B6h)	LSB	MSB	00	00	00	00	00	Total erase fail count
187 (BBh)	LSB			MSB	00	00	00	Uncorrectable error count
192 (C0h)	LSB	MSB	00	00	00	00	00	Power-Off Retract Count
194 (C2h)	MSB	00	00	00	00	00	00	Controlled temperature
195 (C3h)	LSB			MSB	00	00	00	Hardware ECC recovered
196 (C4h)	LSB			MSB	00	00	00	Reallocation event count
198 (C6h)	LSB			MSB	00	00	00	Uncorrectable error count off-line
199 (C7h)	LSB	MSB	00	00	00	00	00	UltraDMA CRC error count
225 (E1h)	LSB						MSB	Total LBAs written (each write unit = 32MB)
232 (E8h)	LSB	MSB	00	00	00	00	00	Available reserved space
241 (F1h)	LSB						MSB	Total LBAs written (each write unit = 32MB)
242 (F2h)	LSB						MSB	Total LBAs read (each write unit = 32MB)

6. Part Number Rule

CODE	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19	20	21
	D	G	S	2	5	-	3	2	G	D	8	1	B	C	1	Q	C	(P)	-	X	X
Description	Disk	2.5″ SATA SSD 3MG2-P					Capacity			Category			Flash mode	Operation Temp.	Internal Control	CH.	Flash	icell		Customized Code	

Definition

Code 1st (Disk)
D : Disk

Code 2nd ~ 5th (Form Factor)
GS25: 2.5″ SATA SSD 3MG2-P (EverGreen Series)

Code 7th ~9th (Capacity)
08G: 8GB
16G: 16GB
32G: 32GB
64G: 64GB
A28: 128GB
B56: 256GB
C12:512GB
01T: 1TB
02T: 2TB

Code 10th ~12th (Series)
D81: 2.5″ SATA SSD 3MG2-P

Code 13th (Flash mode)
B: Synchronous Flash for Toshiba 15nm

Code 14th (Operation Temperature)
C: Standard Grade (0℃~ +70℃)
W: Industrial Grade (-40℃~ +85℃)

Code 15th (Internal control)
1/A: Full size PCBA compliant to 7mm height housing
2/A*: Full size PCBA compliant to 9mm height housing
3: Slim PCBA compliant to 7mm height housing
*A in for 2TB only

Code 16th (Channel of data transfer)
S: Single Channel
D: Dual Channels
Q: Quad Channels

Code 17th (Flash Type)
C: Toshiba MLC

Code 18th (iCell)
P: iCell, reserved for optional function

Code 20th ~21th (Customized code)

Appendix

宜鼎國際股份有限公司
Innodisk Corporation

Tel:(02)7703-3000 Fax:(02) 7703-3555 Internet: http://www.innodisk.com/

RoHS 自我宣告書(RoHS Declaration of Conformity)

Manufacturer Product: All Innodisk EM Flash and Dram products

一、 宜鼎國際股份有限公司（以下稱本公司）特此保證售于貴公司之所有產品，當符合歐盟 2011/65/EU 及(EU) 2015/863 關於 RoHS 之規範要求。

Innodisk Corporation declares that all products sold to the company, are complied with European Union RoHS Directive (2011/65/EU) and (EU) 2015/863 requirement.

二、 本公司同意因本保證書或與本保證書相關事宜有所爭議時，雙方宜友好協商，達成協議。

Innodisk Corporation agrees that both parties shall settle any dispute arising from or in connection with this Declaration of Conformity by friendly negotiations.

三、 本公司聲明我們的產品符合 RoHS 指令的附件中 (7a)、(7c-I)允許豁免。

We declare, our products permitted by the following exemptions specified in the Annex of the RoHS directive.

※ (7a) Lead in high melting temperature type solders(i.e. lead-based alloys containing 85% by weight or more lead).

※ (7C-I) Electrical and electronic components containing lead in a glass or ceramic other than dielectric ceramic in capacitors, e.g. piezoelectric devices, or in a glass or ceramic matrix compound.

Name of hazardous substance	Limited of RoHS ppm（mg/kg）
鉛（Pb）	＜ 1000 ppm
汞（Hg）	＜ 1000 ppm
鎘（Cd）	＜ 100 ppm
六價鉻（Cr 6+）	＜ 1000 ppm
多溴聯苯（PBBs）	＜ 1000 ppm
多溴二苯醚（PBDEs）	＜ 1000 ppm
鄰苯二甲酸二(2-乙基己基)酯（DEHP）	＜ 1000 ppm
鄰苯二甲酸丁酯苯甲酯（BBP）	＜ 1000 ppm
鄰苯二甲酸二丁酯（DBP）	＜ 1000 ppm
鄰苯二甲酸二異丁酯（DIBP）	＜ 1000 ppm

立　保　證　書　人　(Guarantor)

Company name 公司名稱：　Innodisk Corporation　宜鼎國際股份有限公司

Company Representative 公司代表人：　Randy Chien　簡川勝

innodisk

宜鼎國際股份有限公司
Innodisk Corporation

Company Representative Title 公司代表人職稱： ___Chairman 董事長___

Date 日期： ___2018___ / ___07___ / ___01___

宜鼎國際股份有限公司
Innodisk Corporation
REACH Declaration

Tel:(02)7703-3000 Fax:(02) 7703-3555 Internet: http://www.innodisk.com/

We hereby confirm that the product(s) delivered to

Innodisk P/N	Description
All Innodisk EM FLASH Products	

☐ contain(s) no hazardous substances or constituents exceeding the defined threshold 0.1 % by weight in homogenous material if not otherwise specified, as described in the candidate list table currently including 197 substances and shown on the ECHA website (http://echa.europa.eu/de/candidate-list-table).

☑ contain(s) one or more hazardous substances or constituents exceeding 0.1 % by weight in homogenous material if not otherwise specified in candidate list table. Where the threshold value is exceeded, the substances in question are to be declared in accompanying Appendix A .

☑ Comply with REACH Annex XVII.

Guarantor

Company name 公司名稱： Innodisk Corporation 宜鼎國際股份有限公司

Company Representative 公司代表人： Randy Chien 簡川勝

Company Representative Title 公司代表人職稱： Chairman 董事長

Date 日期： 2019 / 01 / 31

Certificate

Issue Date: April 14, 2016
Ref. Report No.   ISL-15LE018CE-1

Product Name   :   2.5" SATA SSD
Model(s)   :   2.5" SATA SSD 3$*#-&
                    $:Flash type: (S:SLC, I:iSLC, M:MLC)
                    *:Product line: (E:Embedded, G:EverGreen, R:InnoRobust)
                    #:Controller: (empty:106/107/167, 2:201/ 202, 3:108/109/170, 4~9:Others)
                    &:Product feature: (P:with DRAM, empty:without DRAM)
Responsible Party   :   Innodisk Corporation
Address   :   5F.No.237, Sec. 1, Datong Rd., Xizhi Dist., New Taipei City 221, Taiwan
                    (R.O.C.)

We, International Standards Laboratory, hereby certify that:

The device bearing the trade name and model specified above has been shown to comply with the applicable technical standards as indicated in the measurement report and was tested in accordance with the measurement procedures specified in European Council Directive- EMC Directive 2004/108/EC (marketed before 2016/04/19) 2014/30/EU (marketed after 2016/04/20). The device was passed the test performed according to :

CE

Standards:
   EN 55022: 2010+AC2011 and CISPR 22: 2008 (modified)
   EN 61000-3-2:2014 and IEC 61000-3-2:2014
   EN 61000-3-3: 2013 and IEC 61000-3-3: 2013
   EN 55024: 2010 and CISPR 24: 2010
   EN 61000-4-2: 2009 and IEC 61000-4-2: 2008
   EN 61000-4-3: 2006+A1: 2008 +A2: 2010 and
   IEC 61000-4-3:2006+A1: 2007+A2: 2010
   EN 61000-4-4:2012 and IEC 61000-4-4:2012

I attest to the accuracy of data and all measurements reported herein were performed by me or were made under my supervision and are correct to the best of my knowledge and belief. I assume full responsibility for the completeness of these measurements and vouch for the qualifications of all persons taking them.

International Standards Laboratory

W.H. Chang / Director

Certificate

Issue Date: January 16, 2015
Ref. Report No. ISL-15LE018FB

Product Name : 2.5" SATA SSD
Model(s) : 2.5" SATA SSD 3$*#-& ($:Flash type: (S:SLC,I:iSLC,M:MLC) *: Product line: (E:Embedded, G: EverGreen, R: InnoRobust) #:controller: (empty:106/107/167/170, 2: 201/ 202, 3:108/109) &: Product feature: (P: with DRAM, empty: without DRAM))
Applicant : Innodisk Corporation
Address : 5F.No.237, Sec. 1, Datong Rd., Xizhi Dist., New Taipei City 221, Taiwan (R.O.C.)

We, **International Standards Laboratory**, hereby certify that:

The device bearing the trade name and model specified above has been shown to comply with the applicable technical standards as indicated in the measurement report and was tested in accordance with the measurement procedures specified. (refer to Test Report if any modifications were made for compliance).

FC

Standards:

FCC CFR Title 47 Part 15 Subpart B: 2012- Section 15.107 and 15.109
ANSI C63.4-2009
Industry Canada Interference-Causing Equipment Standard ICES-003 Issue 5: 2012

Class B

I attest to the accuracy of data and all measurements reported herein were performed by me or were made under my supervision and are correct to the best of my knowledge and belief. I assume full responsibility for the completeness of these measurements and vouch for the qualifications of all persons taking them.

International Standards Laboratory

Jim Chu / Director